

T495, Tantalum, MnO2 Tantalum, 6.8 uF, 10%, 50 VDC, SMD, MnO2, Molded, Low ESR, 190 mOhms, 7343, Height Max = 3.1mm



General Information	
Series:	T495
Dielectric:	MnO2 Tantalum
Style:	SMD Chip
Description:	SMD, MnO2, Molded, Low ESR
Features:	Low ESR
RoHS:	Yes
Termination:	Tin
AEC-Q200:	No
Shelf Life:	156 Weeks
MSL:	1

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.6mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm

Specifications	
Capacitance:	6.8 uF
Capacitance Tolerance:	10%
Voltage DC:	50 VDC (85C), 33.5 VDC (125C)
Temperature Range:	-55/+125°C
Rated Temperature:	85°C
Dissipation Factor:	6% 120Hz 25C
Failure Rate:	N/A
Resistance:	190 mOhms (100kHz 25C)
Ripple Current:	889 mA (rms, 100kHz 25C), 800.1 mA (rms, 85C), 355.6 mA (rms, 125C)
Leakage Current:	3.4 uA (5min 25°C)

Packaging Specifications	
Weight:	446.84 mg
Packaging:	T&R, 178mm
Packaging Quantity:	500

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